NSN 5962-00-506-7606

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Between 1.220 inches and 1.290 inches

Body Width:

Between 0.520 inches and 0.550 inches

Body Height:

Between 0.090 inches and 0.150 inches

Maximum Power Dissipation Rating:

500.0 milliwatts

Operating Tempurature Range:

-55.0/+125.0 degrees celsius

Storage Tempurature Range:

-65.0/+150.0 degrees celsius

Features Provided:

Monolithic and hermetically sealed and negative outputs and high speed and w/decoded output and bipolar and programmable and expandable and wire-or outputs and w/enable and w/disable

Inclosure Material:

Ceramic and glass

Inclosure Configuration:

Dual-in-line

Output Logic Form:

P-type metal oxide-semiconductor logic

Input Circuit Pattern:

11 input

Case Outline Source And Designator:

-0-015-ag joint electron device engineering council

Terminal Surface Treatment:

Gold

Voltage Rating And Type Per Characteristic:

0.3 volts power source

Memory Device Type:

Rom

Memory Capacity:

Unknown

Precious Material And Location:

Terminals gold

Precious Material:

Gold

Test Data Document:

94117-310294 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing)

Terminal Type And Quantity:

24 printed circuit

Shelf Life:

N/a

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Demilitarization:

Yes - demil/mli

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